

Quad buffers (3-State)

74F125, 74F126

FEATURE

- High impedance NPN base inputs for reduced loading (20µA in High and Low states)

TYPE	TYPICAL PROPAGATION DELAY	TYPICAL SUPPLY CURRENT (TOTAL)
74F125	5.0ns	23mA
74F126	5.0ns	26mA

ORDERING INFORMATION

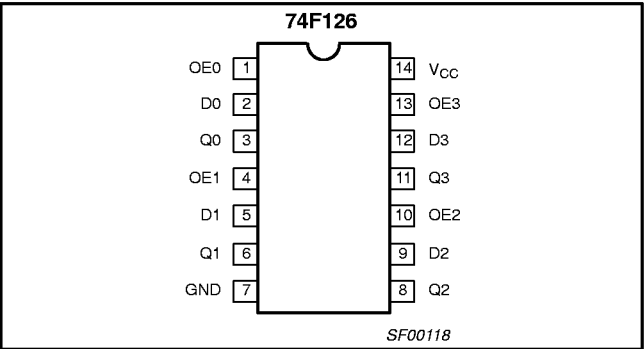
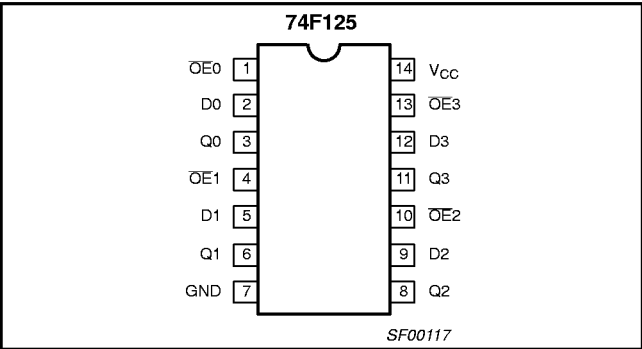
DESCRIPTION	COMMERCIAL RANGE V _{CC} = 5V ±10%, T _{amb} = 0°C to +70°C
14-pin plastic DIP	N74F125N, N74F126N
14-pin plastic SO	N74F125D, N74F126D

INPUT AND OUTPUT LOADING AND FAN OUT TABLE

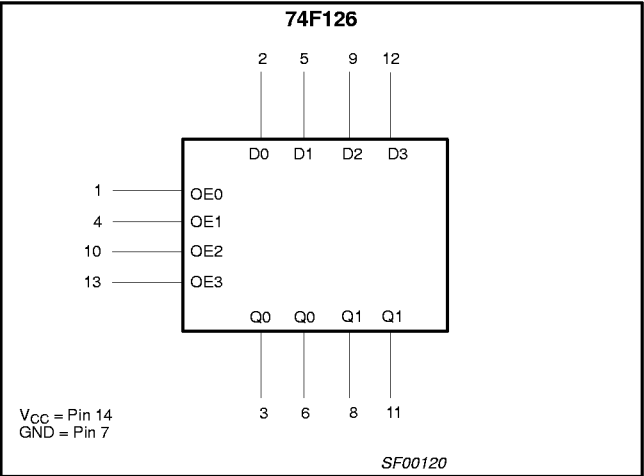
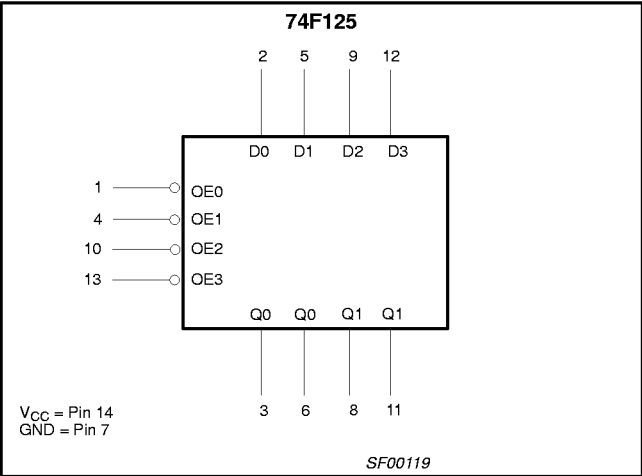
PINS	DESCRIPTION	74F (U.L.) HIGH/LOW	LOAD VALUE HIGH/LOW
D0–D3	Data inputs	1.0/0.033	20µA/20µA
OE0–OE3	Output Enable inputs (active Low), 74F125	1.0/0.033	20µA/20µA
OE0–OE3	Output Enable inputs (active High), 74F126	1.0/0.033	20µA/20µA
Q0–Q3	Data outputs	750/106.7	15mA/64mA

NOTE: One (1.0) FAST unit load is defined as: 20µA in the High state and 0.6mA in the Low state.

PIN CONFIGURATIONS



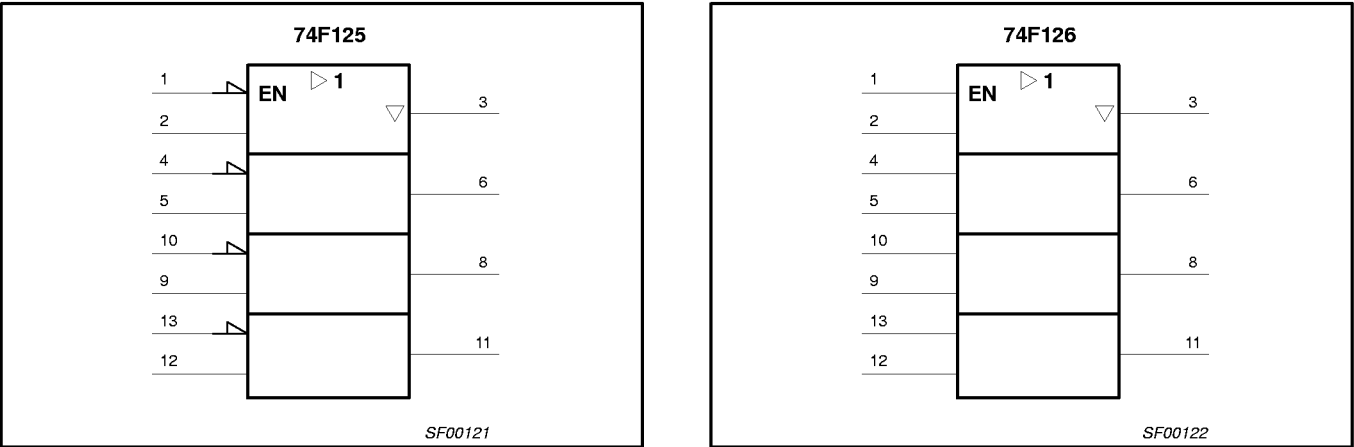
LOGIC SYMBOLS



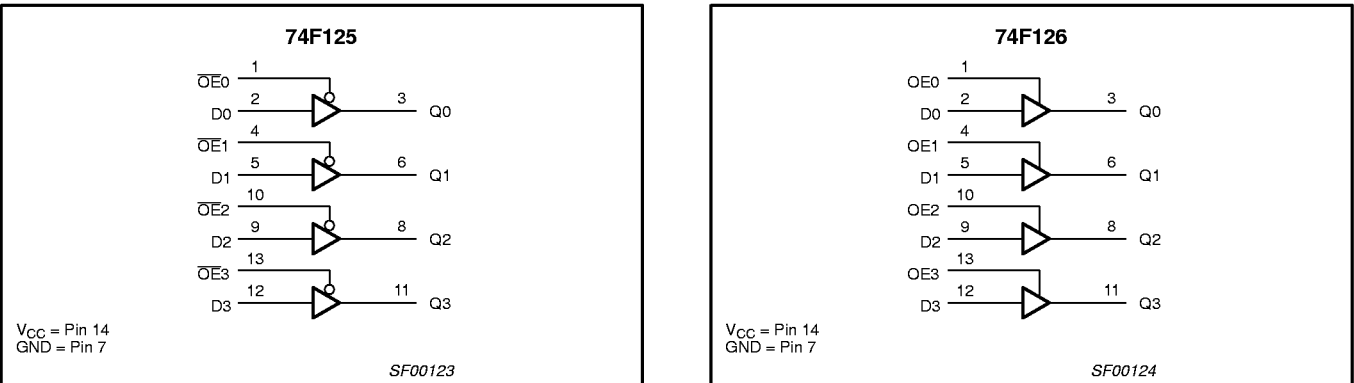
Quad buffers (3-State)

74F125, 74F126

IEC/IEEE SYMBOLS



LOGIC DIAGRAMS



FUNCTION TABLE, 74F125

I INPUTS		OUTPUT
$\overline{OEn}$	Dn	Qn
L	L	L
L	H	H
H	X	Z

FUNCTION TABLE, 74F126

I INPUTS		OUTPUT
OEn	Dn	Qn
H	L	L
H	H	H
L	X	Z

NOTES TO THE FUNCTION TABLES:
H = High voltage level
L = Low voltage level
X = Don't care
Z = High impedance "off" state

ABSOLUTE MAXIMUM RATINGS

(Operation beyond the limit set forth in this table may impair the useful life of the device.
Unless otherwise noted these limits are over the operating free-air temperature range.)

SYMBOL	PARAMETER	RATING	UNIT
V_{CC}	Supply voltage	-0.5 to +7.0	V
V_{IN}	Input voltage	-0.5 to +7.0	V
I_{IN}	Input current	-30 to +5	mA
V_{OUT}	Voltage applied to output in High output state	-0.5 to V_{CC}	V
I_{OUT}	Current applied to output in Low output state	128	mA
T_{amb}	Operating free-air temperature range	0 to +70	°C
T_{stg}	Storage temperature range	-65 to +150	°C

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74F125, 74F126

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIMITS			UNIT
		MIN	NOM	MAX	
V_{CC}	Supply voltage	4.5	5.0	5.5	V
V_{IH}	High-level input voltage	2.0			V
V_{IL}	Low-level input voltage			0.8	V
I_{IK}	Input clamp current			-18	mA
I_{OH}	High-level output current			-15	mA
I_{OL}	Low-level output current			64	mA
T_{amb}	Operating free air temperature range	0		+70	°C

DC ELECTRICAL CHARACTERISTICS

(Over recommended operating free-air temperature range unless otherwise noted.)

SYMBOL	PARAMETER			TEST CONDITIONS ¹		LIMITS			UNIT	
						MIN	TYP ²	MAX		
V _{OH}	High-level output voltage			V _{CC} = MIN, V _{IL} = MAX, V _{IH} = MIN	I _{OH} =−3mA	±10%V _{CC}	2.4		V	
						±5%V _{CC}	2.7	3.3	V	
					I _{OH} =−15mA	±10%V _{CC}	2.0		V	
						±5%V _{CC}	2.0		V	
V _{OL}	Low-level output voltage			V _{CC} = MIN, V _{IL} = MAX, V _{IH} = MIN	I _{OH} = MAX	±10%V _{CC}			0.55	V
						±5%V _{CC}		0.42	0.55	V
V _{IK}	Input clamp voltage			V _{CC} = MIN, I _I = I _{IK}				−0.73	−1.2	V
I _I	Input current at maximum input voltage			V _{CC} = 0.0V, V _I = 7.0V					100	μA
I _{IH}	High-level input current			V _{CC} = MAX, V _I = 2.7V					20	μA
I _{IL}	Low-level input current			V _{CC} = MAX, V _I = 0.5V					−20	μA
I _{OZH}	Off-state output current, High-level voltage applied			V _{CC} = MAX, V _O = 2.7V					50	μA
I _{OZL}	Off-state output current, Low-level voltage applied			V _{CC} = MAX, V _O = 0.5V					−50	μA
I _{OS}	Short circuit output current ³			V _{CC} = MAX		−100			−225	mA
I _{CC}	Supply current (total)		74F125	I _{CCH}	V _{CC} = MAX	OE̅n = GND, Dn = 4.5V		17	24	mA
						OE̅n = Dn = GND		28	40	mA
						OE̅n = Dn = 4.5V		25	35	mA
			74F126	I _{CCH}	V _{CC} = MAX	OE̅n = Dn = 4.5V		20	30	mA
						OE̅n = 4.5V, Dn = GND		32	48	mA
						OE̅n = GND, Dn = 4.5V		26	39	mA

NOTES:

- For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions for the applicable type.
- All typical values are at $V_{CC} = 5\text{V}$, $T_{amb} = 25^\circ\text{C}$.
- Not more than one output should be shorted at a time. For testing I_{OS} , the use of high-speed test apparatus and/or sample-and-hold techniques are preferable in order to minimize internal heating and more accurately reflect operational values. Otherwise, prolonged shorting of a High output may raise the chip temperature well above normal and thereby cause invalid readings in other parameter tests. In any sequence of parameter tests, I_{OS} tests should be performed last.

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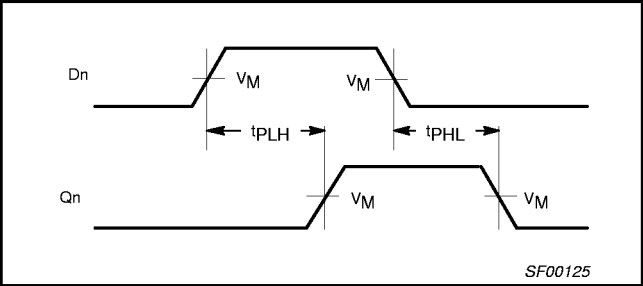
74F125, 74F126

AC ELECTRICAL CHARACTERISTICS

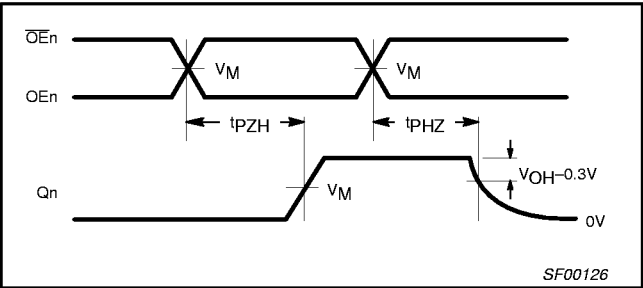
SYMBOL	PARAMETER		TEST CONDITION	LIMITS					UNIT
				V _{CC} = +5.0V T _{amb} = +25°C C _L = 50pF, R _L = 500Ω			V _{CC} = +5.0V ± 10% T _{amb} = 0°C to +70°C C _L = 50pF, R _L = 500Ω		
				MIN	TYP	MAX	MIN	MAX	
t _{PLH} t _{PHL}	Propagation delay Dn to Qn	74F125	Waveform 1	2.0 3.0	4.0 5.5	6.0 7.5	2.0 3.0	6.5 8.0	ns
t _{PZH} t _{PZL}	Output Enable time to High or Low level		Waveform 2 Waveform 3	3.5 4.0	5.5 6.0	7.5 8.0	3.5 4.0	8.5 9.0	ns
t _{PHZ} t _{PLZ}	Output Disable time from High or Low level		Waveform 2 Waveform 3	1.5 1.5	3.5 3.5	5.0 5.5	1.5 1.5	6.0 6.0	ns
t _{PLH} t _{PHL}	Propagation delay Dn to Qn	74F126	Waveform 1	2.0 3.0	4.0 5.5	6.5 8.0	2.0 3.0	7.0 8.5	ns
t _{PZH} t _{PZL}	Output Enable time to High or Low level		Waveform 2 Waveform 3	4.0 4.0	6.0 6.0	7.5 8.0	3.5 3.5	8.5 8.5	ns
t _{PHZ} t _{PLZ}	Output Disable time from High or Low level		Waveform 2 Waveform 3	2.0 3.0	4.5 5.5	6.5 7.5	2.0 3.0	7.5 8.0	ns

AC WAVEFORMS

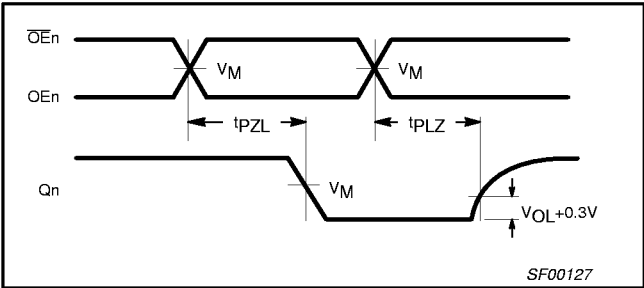
For all waveforms, $V_M = 1.5V$.



Waveform 1. Propagation Delay for Input to Output



Waveform 2. 3-State Output Enable Time to High Level and Output Disable Time from High Level

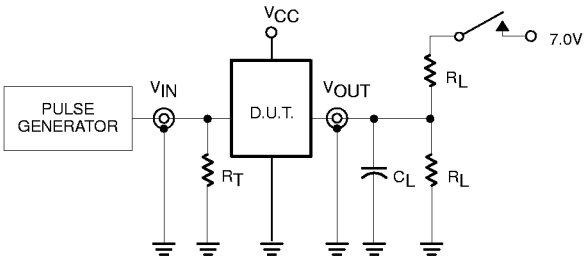


Waveform 3. 3-State Output Enable Time to Low Level and Output Disable Time from Low Level

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74F125, 74F126

TEST CIRCUIT AND WAVEFORM

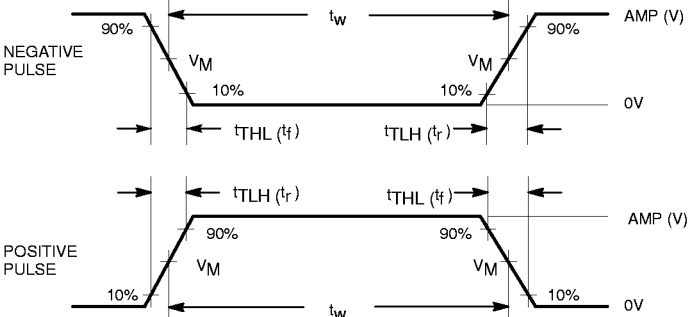


The test circuit shows a Pulse Generator connected to the input VIN of a D.U.T. (Device Under Test). The input line has a termination resistor RT to ground. The output VOUT is connected to a load resistor RL and a load capacitor CL in parallel, which is then connected to a switch. The switch can connect the output to either a 7.0V source or ground. The circuit is powered by VCC.

Test Circuit for Open Collector Outputs

TEST	SWITCH
tPLZ	closed
tPZL	closed
All other	open

DEFINITIONS:
RL = Load resistor;
see AC electrical characteristics for value.
CL = Load capacitance includes jig and probe capacitance;
see AC electrical characteristics for value.
RT = Termination resistance should be equal to ZOUT of pulse generators.



The diagram shows two input pulse waveforms: a Negative Pulse and a Positive Pulse. Both pulses are measured relative to 0V. The pulse amplitude is VM. The pulse width is tw. The rise time (tTLH) and fall time (tTHL) are measured from 10% to 90% of the pulse amplitude. The output is labeled AMP (V).

Input Pulse Definition

family	INPUT PULSE REQUIREMENTS					
	amplitude	VM	rep. rate	tw	tTLH	tTHL
74F	3.0V	1.5V	1MHz	500ns	2.5ns	2.5ns

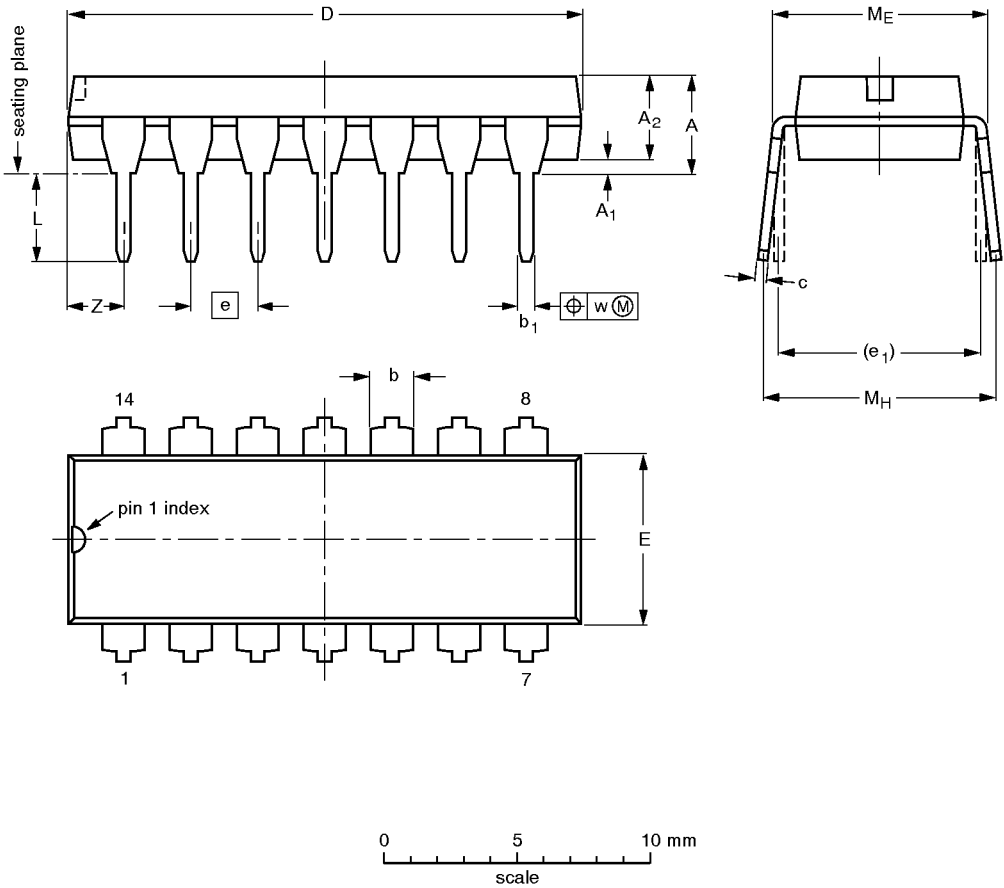
SF00128

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DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	c	D ⁽¹⁾	E ⁽¹⁾	e	e ₁	L	M _E	M _H	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.13	0.53 0.38	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.2
inches	0.17	0.020	0.13	0.068 0.044	0.021 0.015	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.087

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

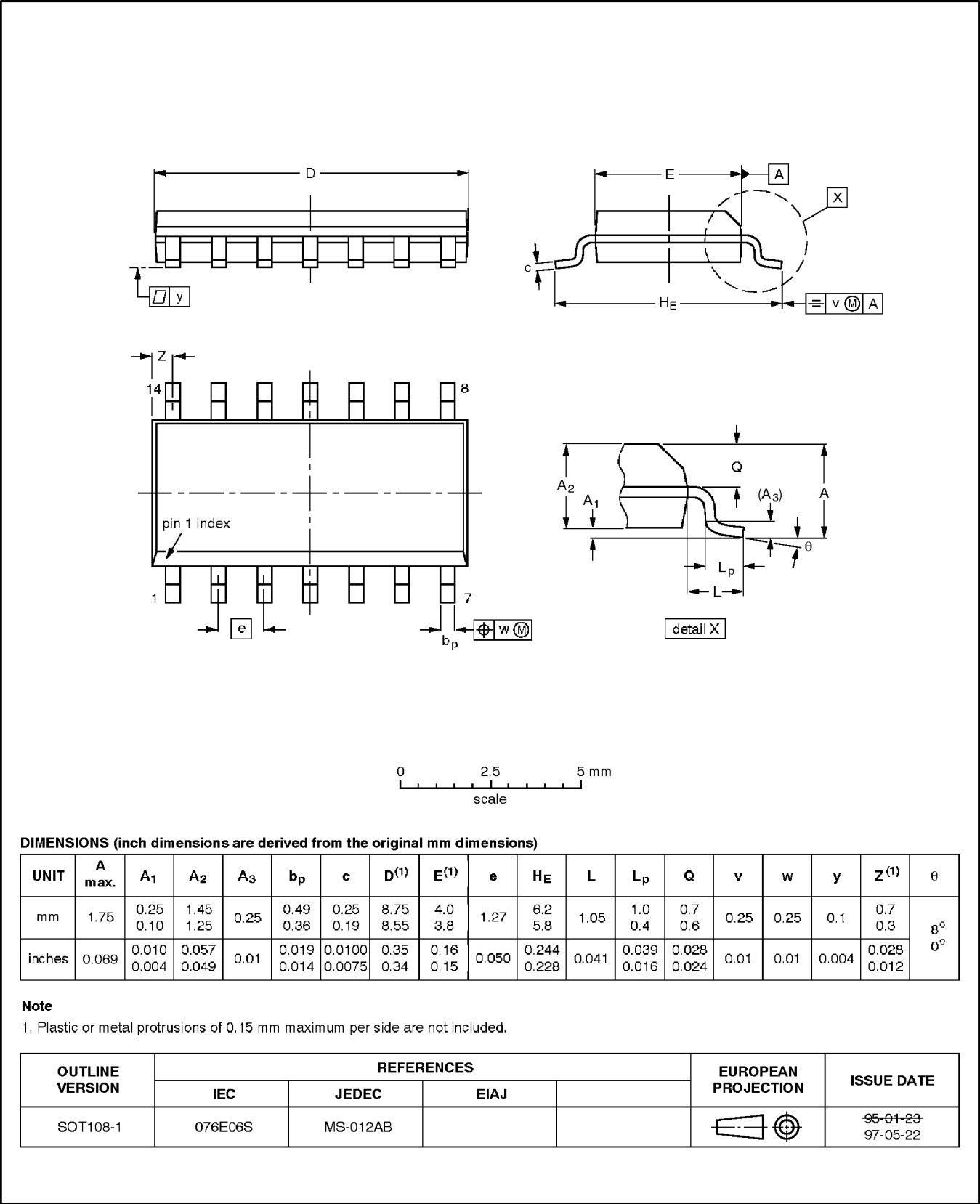
OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT27-1	050G04	MO-001AA				92-11-17 95-03-11

Quad buffers (3-State)

74F125, 74F126

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



Quad buffers (3-State)

74F125, 74F126

NOTES

Quad buffers (3-State)

74F125, 74F126

Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

[1] Please consult the most recently issued datasheet before initiating or completing a design.

Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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